

Data sheet acquired from Harris Semiconductor SCHS155C

CD54HC164, CD74HC164, CD54HCT164

High-Speed CMOS Logic 8-Bit Serial-In/Parallel-Out Shift Register

October 1997 - Revised August 2003

Features

- · Buffered Inputs
- Asynchronous Master Reset
- Typical $f_{MAX} = 60MHz$ at $V_{CC} = 5V$, $C_L = 15pF$, $T_{\Delta} = 25^{\circ}C$
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC164 and 'HCT164 are 8-bit serial-in parallel-out shift registers with asynchronous reset. Data is shifted on the positive edge of Clock (CP). A LOW on the Master Reset (\overline{MR}) pin resets the shift register and all outputs go to the LOW state regardless of the input conditions. Two Serial Data inputs (DS1 and DS2) are provided, either one can be used as a Data Enable control.

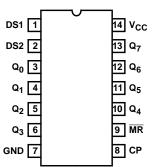
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC164F3A	-55 to 125	14 Ld CERDIP
CD54HCT164F3A	-55 to 125	14 Ld CERDIP
CD74HC164E	-55 to 125	14 Ld PDIP
CD74HC164M	-55 to 125	14 Ld SOIC
CD74HC164MT	-55 to 125	14 Ld SOIC
CD74HC164M96	-55 to 125	14 Ld SOIC
CD74HCT164E	-55 to 125	14 Ld PDIP
CD74HCT164M	-55 to 125	14 Ld SOIC
CD74HCT164MT	-55 to 125	14 Ld SOIC
CD74HCT164M96	-55 to 125	14 Ld SOIC

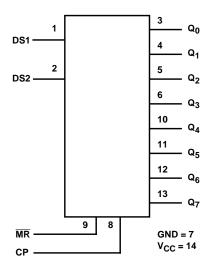
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC164, CD54HCT164 (CERDIP) CD74HC164, CD74HCT164 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

		INP	UTS		OUTPUTS			
OPERATING MODE	MR	СР	DS1	DS2	Q ₀	Q ₁ - Q ₇		
RESET (CLEAR)	L	Х	х	Х	L	L-L		
Shift	Н	↑	1	I	L	90 - 96		
	Н	1	1	h	L	90 - 96		
	Н	1	h	I	L	90 - 96		
	Н	1	h	h	Н	90 - 96		

H= High Voltage Level.

h= High Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition.

I= Low Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition.

L= Low Voltage Level.

X= Don't Care.

 \uparrow = Transition from Low to High Level.

 $\ensuremath{q_{\text{n}}}\xspace=$ Lower Case Letters Indicate The State Of the Reference Input Clock Transition.

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} -0.5V to 7V DC Input Diode Current, I_{IK} DC Output Diode Current, I_{OK} DC Output Source or Sink Current per Output Pin, IO For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$±25mA

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (oC/W)
E (PDIP) Package	80
M (SOIC) Package	86
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES							-				-	
High Level Input	V _{IH}	-	-	2	1.5	ı	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	1	-	3.15	-	3.15	-	V
				6	4.2	ı	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	ı	ı	0.5	-	0.5	-	0.5	V
Voltage				4.5	ı	ı	1.35	-	1.35	-	1.35	V
				6	ı	i	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	٧
Voltage CMOS Loads		V _{IL}	-0.02	4.5	4.4	i	-	4.4	-	4.4	-	٧
			-0.02	6	5.9	ı	-	5.9	-	5.9	-	V
High Level Output			-4	4.5	3.98	-	-	3.84	-	3.7	-	٧
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	٧
Voltage CMOS Loads		V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	٧
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			4	4.5	-	-	0.26	-	0.33	-	0.4	٧
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	٧
Input Leakage Current	II	V _{CC} or GND	-	6	ı	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	lcc	V _{CC} or GND	0	6	ı	-	8	-	80	-	160	μА

DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												-
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS						
Date Shift-In (1, 2)	0.3						
MR	0.9						
Clock	0.7						

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. 360 μ A max at 25 $^{\circ}$ C.

Prerequisite For Switching Function

			25	°C	-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES				-		-	-	_	-
Maximum Clock Frequency	f _{MAX}	2	6	-	5	-	4	-	MHz
		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
MR Pulse Width	t _w	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns

Prerequisite For Switching Function (Continued)

			25	°C	-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
CP Pulse Width	t _W	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Set-up Time	t _{SU}	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns
Hold Time	t _H	2	4	-	4	-	4	-	ns
		4.5	4	-	4	-	4	-	ns
		6	4	-	4	-	4	-	ns
MR to Clock,	t _{REM}	2	80	-	100	-	120	-	ns
Removal Time		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
HCT TYPES	•	•	•	•	•		•	•	•
Maximum Clock Frequency	f _{MAX}	4.5	27	-	22	-	18	-	MHz
MR Pulse Width	t _w	6	18	-	23	-	27	-	ns
CP Pulse Width	t _w	4.5	18	-	23	-	27	-	ns
Set-up Time	t _{SU}	6	12	-	15	-	18	-	ns
Hold Time	t _H	4.5	4	-	4	-	4	-	ns
MR to Clock, Removal Time	t _{REM}	6	16	-	20	-	24	-	ns

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25	o _C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	170	212	255	ns
CP to Q _n			4.5	-	34	43	51	ns
		C _L = 15pF	5	14	-	-	-	ns
		C _L = 50pF	6	-	29	36	43	ns
MR to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	140	175	210	ns
			4.5	-	28	35	42	ns
		C _L = 15pF	5	11	-	-	-	ns
		C _L = 50pF	6	-	24	30	36	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	75	-	110	ns
			4.5	-	15	-	22	ns
			6	-	13	-	19	ns
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	60	-	-	-	MHz
Input Capacitance	C _{IN}	-	-	ı	10	10	10	pF

Switching Specifications Input t_r, t_f = 6ns (Continued)

		TEST		25	°C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	47	-	-	-	pF
HCT TYPES								
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	36	45	54	ns
CP to Q _n		C _L = 15pF	5	15	-	-	-	ns
MR to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	38	46	57	ns
		C _L = 15pF	5	16	-	=	-	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	15	19	22	ns
Input Capacitance	C _{IN}	-	-	-	-	=	-	pF
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	-	54	-	=	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	49	10	10	10	pF

NOTES:

- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per device.
- 4. $P_D = V_{CC}^2 f_i + \sum (C_L V_{CC}^2 + f_O)$ where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

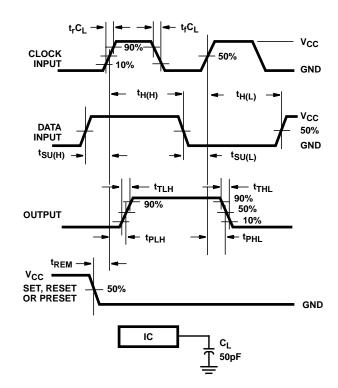


FIGURE 1. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

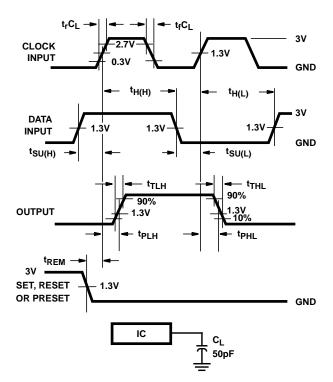


FIGURE 2. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS





25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8970401CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8970401CA CD54HCT164F3A	Samples
CD54HC164F	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC164F	Samples
CD54HC164F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8416201CA CD54HC164F3A	Samples
CD54HCT164F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8970401CA CD54HCT164F3A	Samples
CD74HC164E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC164E	Samples
CD74HC164EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC164E	Samples
CD74HC164M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HC164MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC164M	Samples
CD74HCT164E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT164E	Samples
CD74HCT164EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT164E	Samples





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Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT164M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples
CD74HCT164MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT164M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

25-Sep-2013

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC164, CD54HC164, CD74HC164, CD74HC164:

Catalog: CD74HC164, CD74HCT164

Military: CD54HC164, CD54HCT164

NOTE: Qualified Version Definitions:

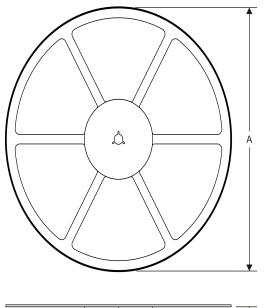
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

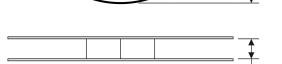
PACKAGE MATERIALS INFORMATION

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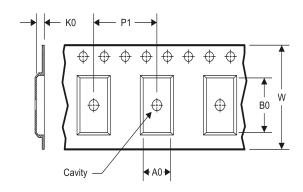
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



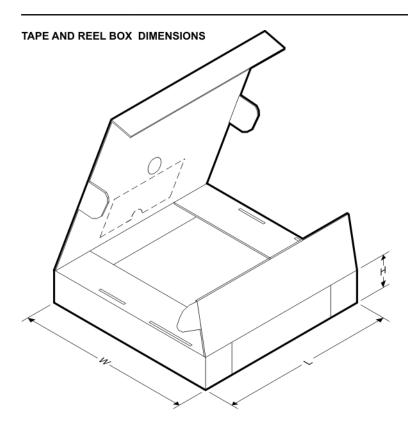
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

All ullilerisions are nomina												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC164M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC164MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT164M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT164MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC164M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC164MT	SOIC	D	14	250	367.0	367.0	38.0
CD74HCT164M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HCT164MT	SOIC	D	14	250	367.0	367.0	38.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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